

KBJ406G thru KBJ410G

Single Phase Glass Passivated Silicon Bridge Rectifier

V_{RRM} = 600 V - 1000 V I_O = 4 A

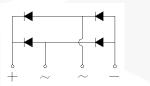
KBJ Package

Features

- · Ideal for printed circuit board
- Reliable low cost construction
- · Plastic material has Underwriters Laboratory
- Flammability Classification 94V-0
- Surge overload rating to 120 Amperes peak
- Types from 50 V to 400 V V_{RRM}
- Not ESD Sensitive

Mechanical Data

Case: Molded plastic Weight: 0.15 ounce, 4.0 grams Mounting torque: 5 inch-lb max







Maximum ratings at Ta = 25 °C (ambient temperature), unless otherwise specified

Parameter	Symbol	Conditions	KBJ406G	KBJ408G	KBJ410G	Unit
Repetitive peak reverse v	oltage V _{RRM}		600	800	1000	V
RMS reverse voltage	V _{RMS}		420	560	700	V
DC blocking voltage	V _{DC}		600	800	1000	V
Operating temperature	Tj		-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T _{stg}		-55 to 150	-55 to 150	-55 to 150	°C

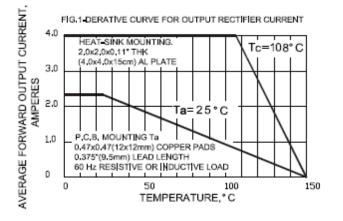
Electrical characteristics at Ta = 25 °C, unless otherwise specified

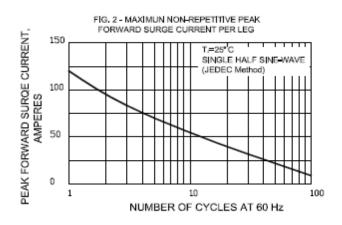
Single phase, half sine wave, 60 Hz, resistive or inductive load For capacitive load derate current by 20%

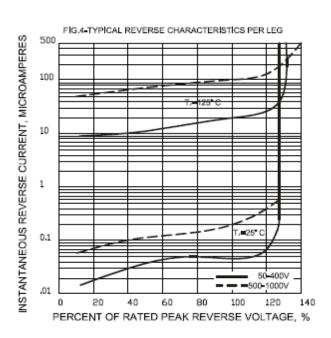
Parameter	Symbol	Conditions	KBJ406G	KBJ408G	KBJ410G	Unit
Maximum average forward rectified current	Ι _ο	T _c = 108 °C	4	4	4	A
		$T_a = 25 \ ^{\circ}C$	2.3	2.3	2.3	
Peak forward surge current	I _{FSM}	8.3 ms single sine-wave	120	120	120	А
Maximum instantaneous forward voltage per leg	V_{F}	$I_F = 4 A$	1.1	1.1	1.1	V
Maximum reverse current at	r I _R	T _a = 25 °C	5	5	5	μΑ
rated DC blocking voltage per leg		T _a = 125 °C	500	500	500	



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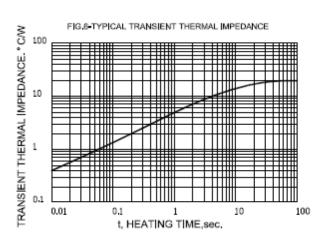
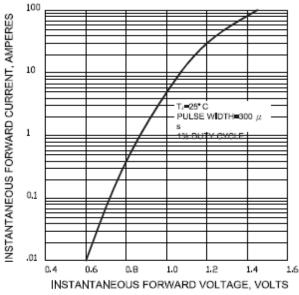
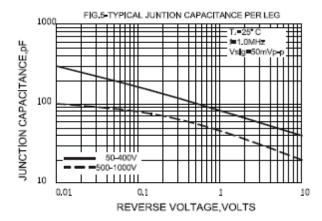


FIG.3-TYPICAL FORWARD CHARACTERISTICS PER LEG



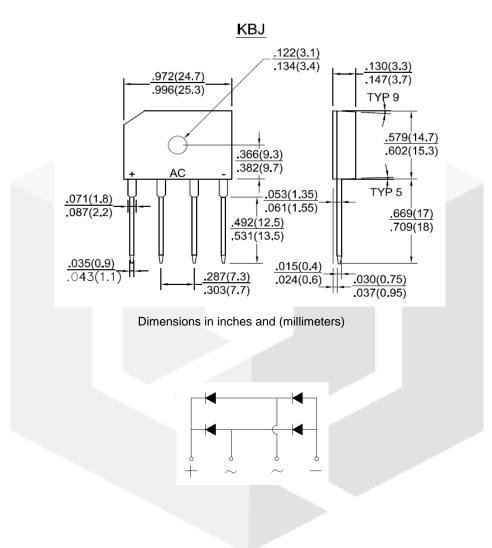






Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



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KBJ408G